## Supporting information

## SF<sub>6</sub> degradation in a $\gamma$ -Al<sub>2</sub>O<sub>3</sub> packed DBD system: Effects of hydration, reactive gases and plasma-induced surface charges

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Fig. S1 1-hour temporal evolution of the voltage ampitude in the Ar discharge. (80 W, 2mm hydrated  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> packing)





Fig. S2 U-I signals during 1-hour temporal discharge test. (80 W, 2mm hydrated γ-Al<sub>2</sub>O<sub>3</sub> packing)



(c) 4 mm hydrated (d) 4 mm dry Fig. S3 Discharge voltage and current signals of two packing systems before and after the hydration (3% SF<sub>6</sub>-97% Ar, input power: 100W)



Fig. S4 Q-V plots of the  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> packing systems before and after the hydration process (3% SF<sub>6</sub> - 97% Ar, 100 mL/min, 100 W)



Fig. S5 FTIR results of the gas mixture after the DBD abatement with hydrated  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> packing (4 mm beads, 3% SF<sub>6</sub> - 97% Ar, 100 mL/min, 80 W)



Fig. S6 Discharge voltage and current signals of the packed bed system with  $H_2O$  or  $O_2$  additions (80 W, 200 mL/min, 3% SF<sub>6</sub>, 4 mm  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> packing)



Fig. S7 Q-V plots for the packed bed systems with and without additional gases (80 W, 200 mL/min, 3% SF<sub>6</sub>, 4 mm  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> packing)



Fig. S8 SF<sub>6</sub> adsorption on three surfaces with the Al<sub>III</sub> site occupied by pre-adsorbed species



Fig.S9 SF<sub>6</sub> adsorption on  $H_2O$  or  $O_2$  pre-adsorbed surface with SF<sub>6</sub> adsorbed at the Al<sub>III</sub> site



(a) O<sub>2</sub> pre-adsorbed

(b) Hydrated surface

Fig. S10 TS process of SF $_6$  initial bond breaking on the O  $_2$  pre-adsorbed and hydrated surfaces



Fig. S11 The differential charge distribution of  $SF_6$  on  $H_2O$  pre-adsorbed  $\gamma$ -Al<sub>2</sub>O surface. The yellow region indicates an increase in charge density and the cyan region indicates a decrease.



Fig. S12 The differential charge distribution of SF<sub>6</sub> adsorbed on the two surfaces with 1.00|e| induced surface charges. The yellow region indicates an increase in charge density and the cyan region indicates a decrease.



Fig. S13 Aggregated surface partial charge of the perfect  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> slab as a function of the electric field

strength



(a) 0.50V/ Å of  $\downarrow$  electric field

(b) 0.80V/ Å of  $\downarrow$  electric field



(c) 0.50V/ Å of  $\uparrow$  electric field

(d) 1.00V/ Å of ↑ electric field

Fig. S14 Differential charge distributions for  $SF_6$  adsorption configurations on the perfect  $\gamma$ -Al<sub>2</sub>O<sub>3</sub> surface under different electric field strengths. The yellow region indicates an increase in charge density and the cyan region indicates a decrease.